

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	3.3029	960.6469 m	N/A
RT2	12.5577	847.5531 m	N/A
RT3	13.9898	1.5363	N/A
RT4	51.1496	1.1555	N/A
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	2.9503 m	19.2427 m	N/A
CT2	16.0156 m	457.2441 u	N/A
CT3	136.5597 m	9.5660 m	N/A
CT4	1.2566	5.4578 m	N/A

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RF1	4.6613	416.5000 m	N/A
RF2	14.6117	1.1870	N/A
RF3	14.6854	1.6845	N/A
RF4	47.0416	1.2120	N/A
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	2.4888 m	354.4541 u	N/A
CF2	11.7823 m	401.9611 u	N/A
CF3	147.7955 m	3.7349 m	N/A
CF4	1.2150	268.1846 u	N/A

**Note**

NA indicates not applicable

